

FIG. 1

[illegible]

3/10

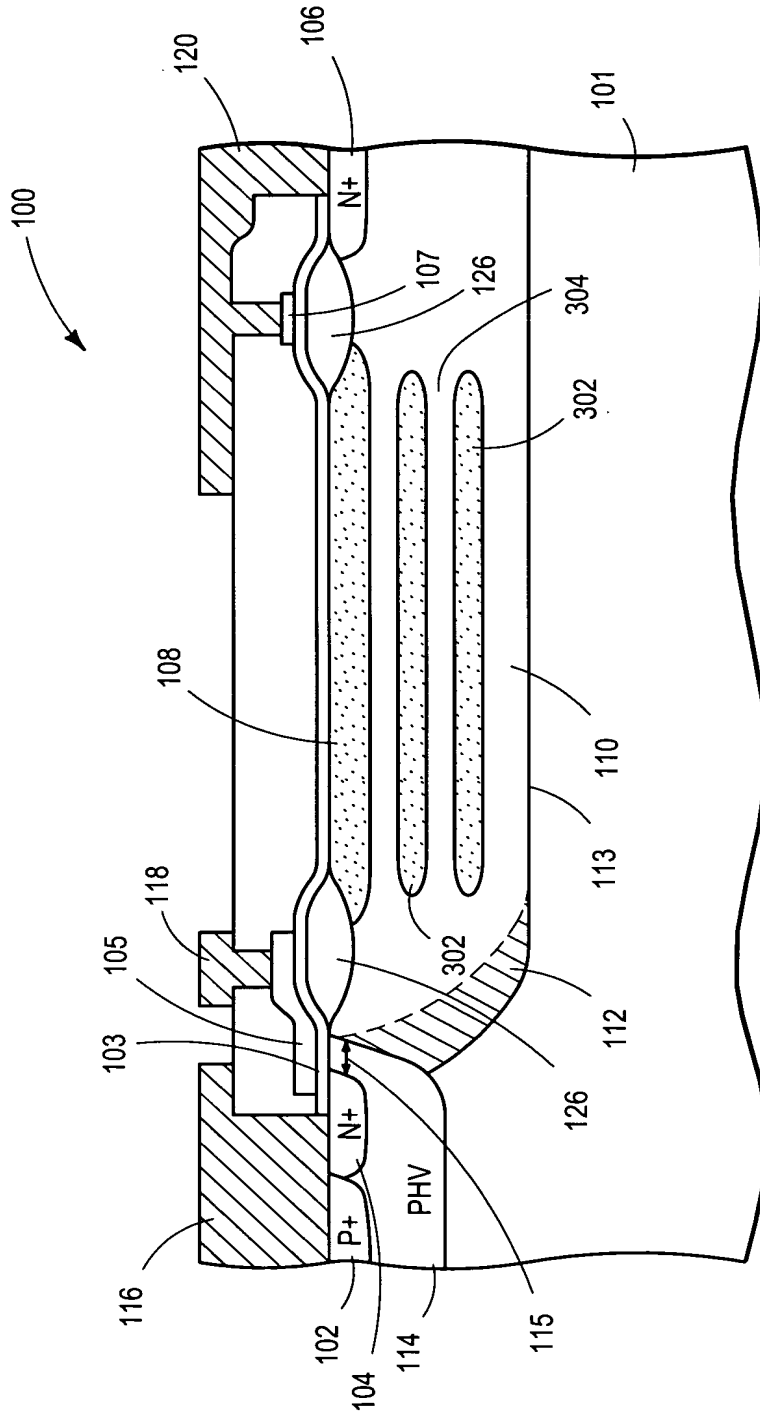


FIG. 3

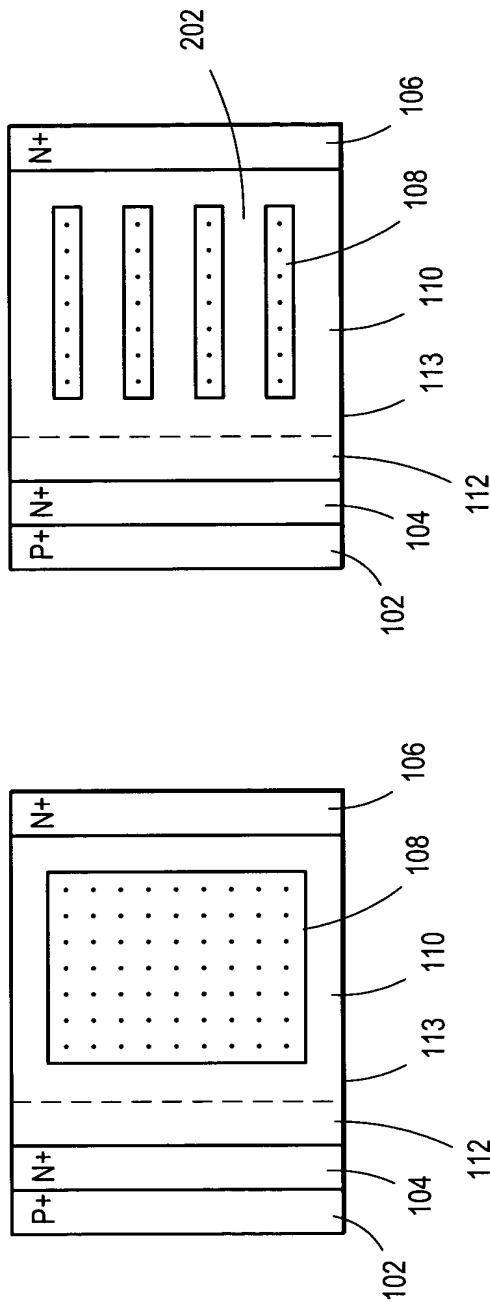


FIG. 4a

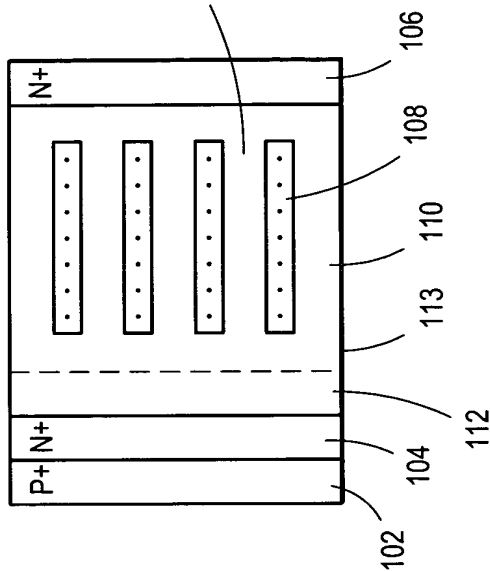


FIG. 4b

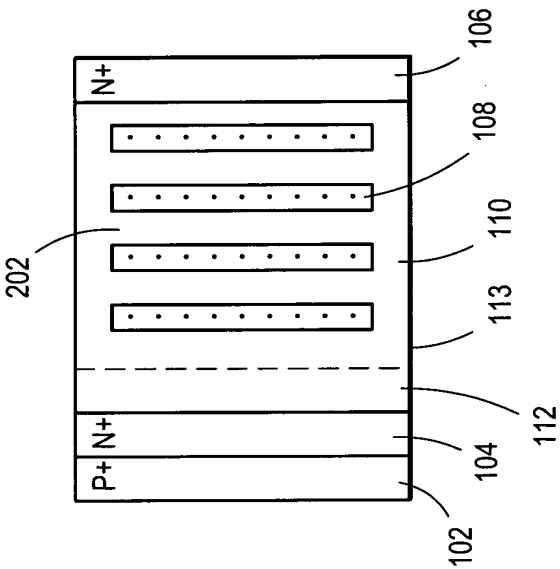


FIG. 4c



5/10

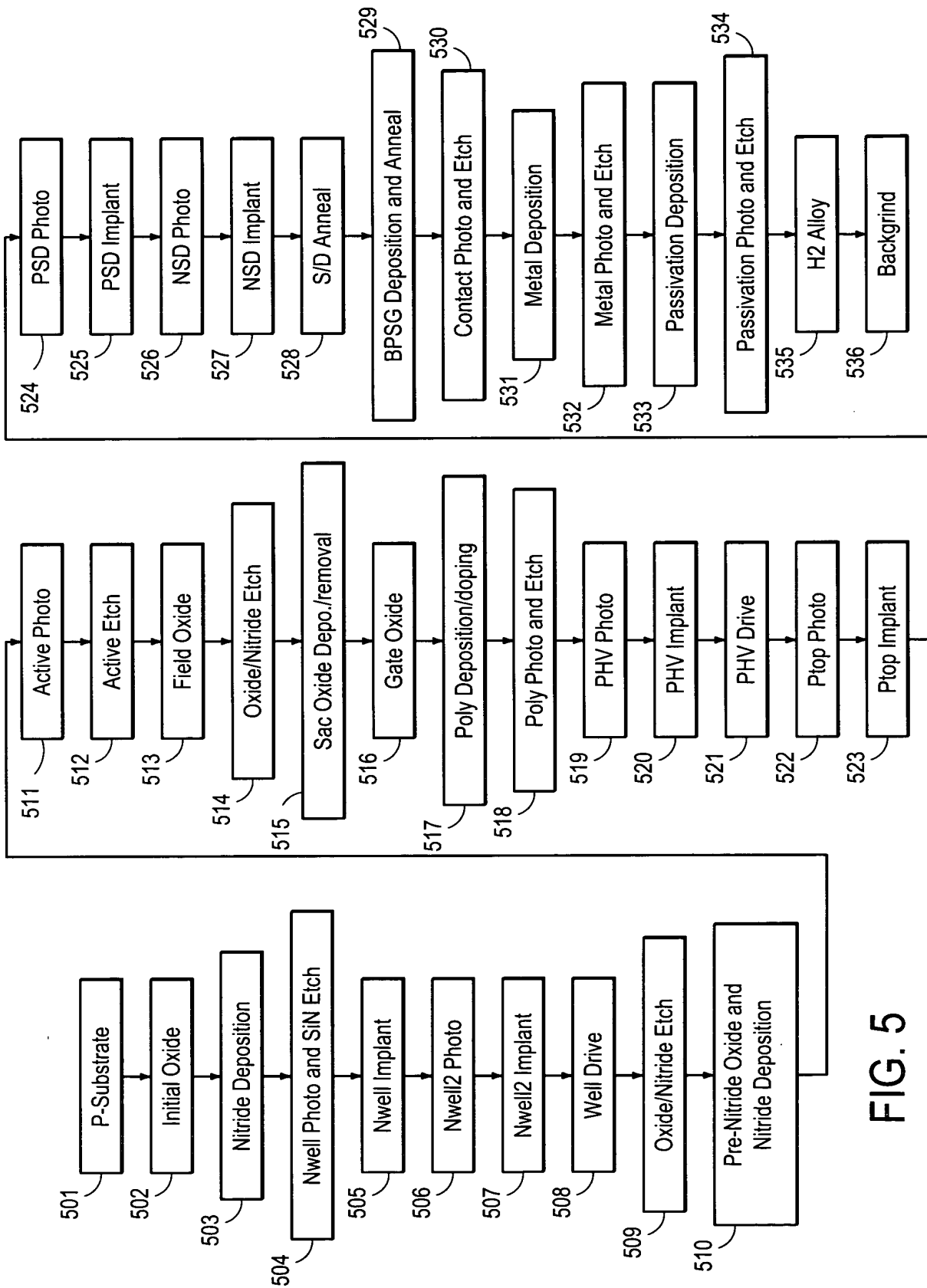


FIG. 5



TITLE: METHOD FOR MANUFACTURING A HIGH VOLTAGE MOSFET
SEMICONDUCTOR DEVICE WITH ENHANCED CHARGE CONTROLLABILITY
INVENTOR: Mohamed Imam et al.
SERIAL NO.: 09/917,731 - DOCKET NO.: ONS00187

6/10

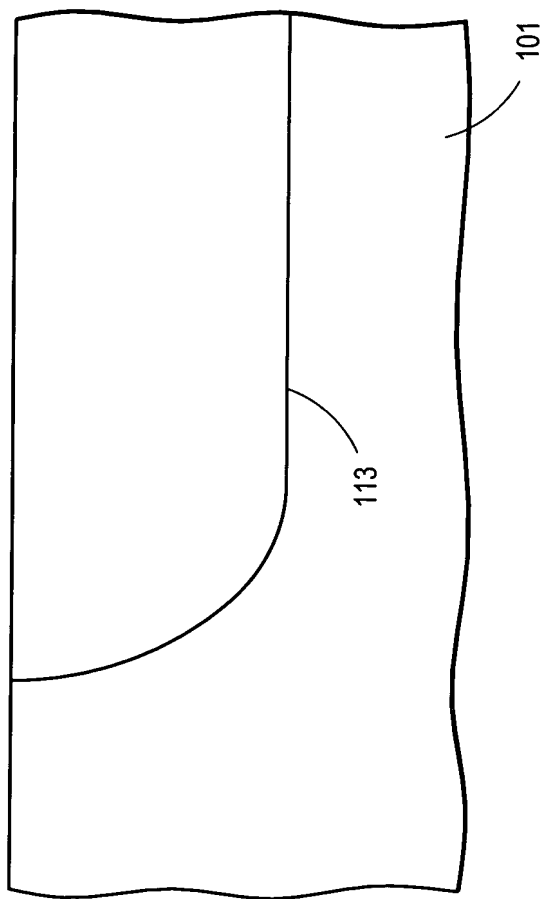


FIG. 6



TITLE: METHOD FOR MANUFACTURING A HIGH VOLTAGE MOSFET
SEMICONDUCTOR DEVICE WITH ENHANCED CHARGE CONTROLLABILITY
INVENTOR: Mohamed Imam et al.
SERIAL NO.: 09/917,731 - DOCKET NO.: ONS00187

7/10

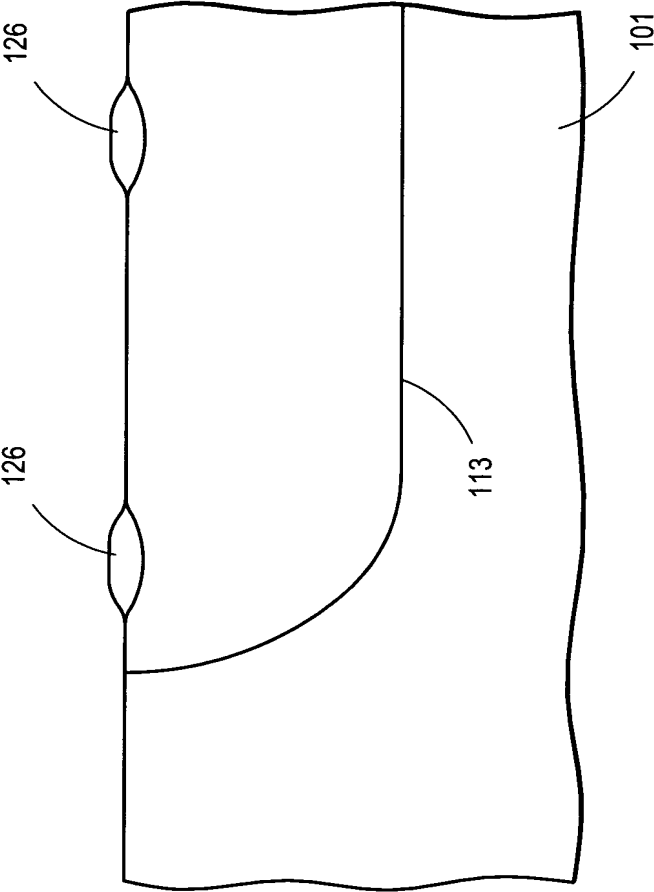


FIG. 7

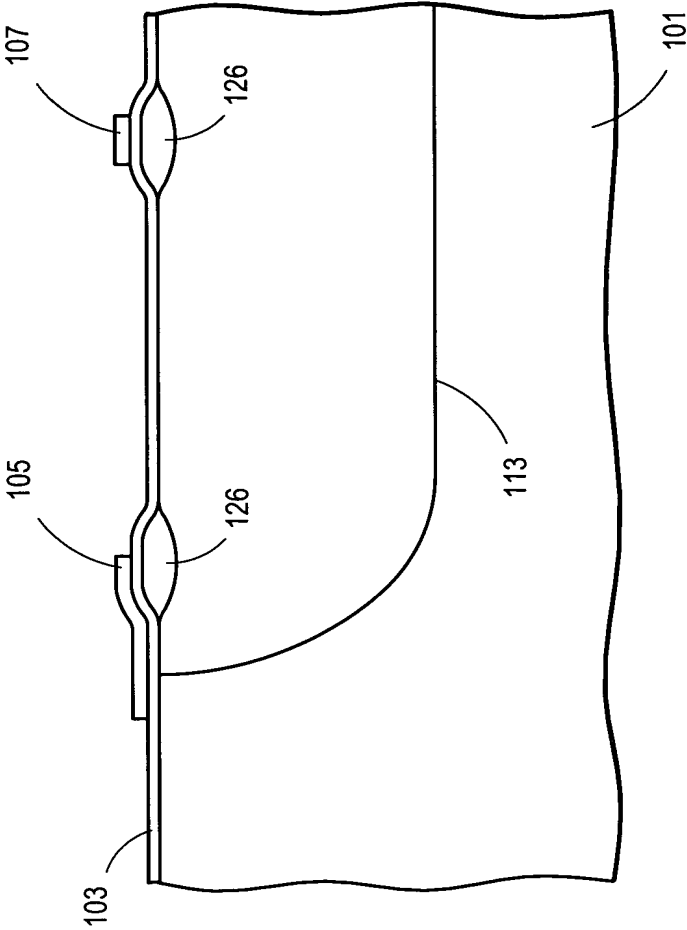


FIG. 8



TITLE: METHOD FOR MANUFACTURING A HIGH VOLTAGE MOSFET
SEMICONDUCTOR DEVICE WITH ENHANCED CHARGE CONTROLLABILITY
INVENTOR: Mohamed Imam et al.
SERIAL NO.: 09/917,731 - DOCKET NO.: ONS00187

9/10

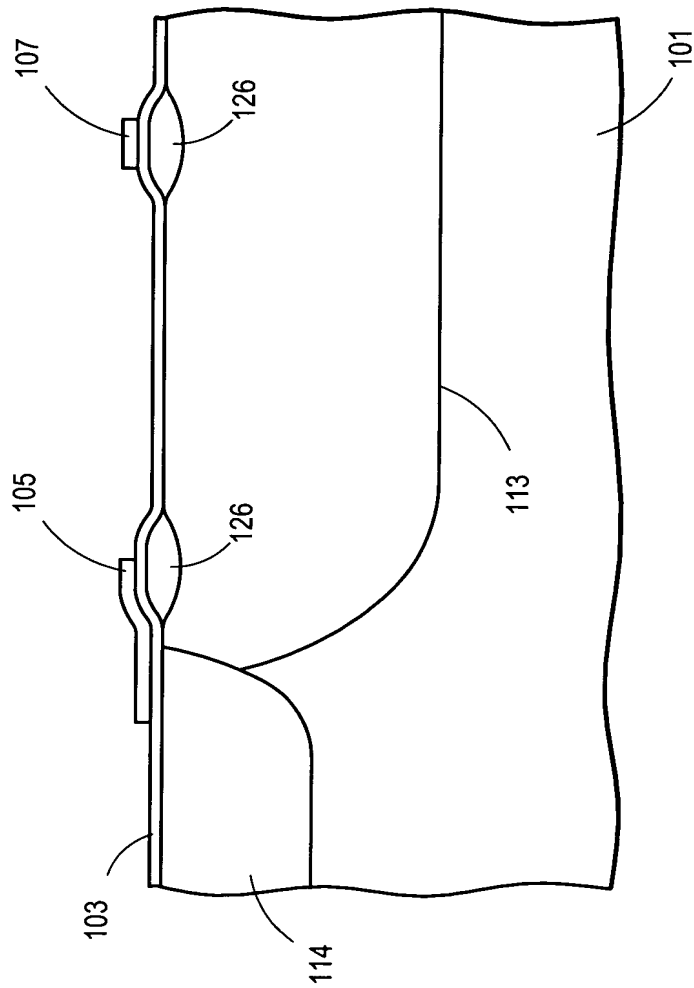


FIG. 9

